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## FC-CVD synthesis FWCNTs for transparent conductor applications

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Online (hybrid)

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## Abstract:

We report transparent conducting films (TCF) of largediameter CNTs from methane-based FC-CVD overcoming the performance-yield tradeoff. Based on the Fe-C-S system, the double-wall CNTs (DWCNTs) with a mean diameter of 4.15 nm and a mean bundle length of 20 um have been produced into TCFs via FC-CVD. After gold chloride solution doping, the TCFs have an excellent performance of 42 ohm/sq sheet resistance at 90% transmittance. Unexpectedly, these highperformance DWCNTs films have an ultra-high yield i.e. production rate, being two orders of magnitude higher than that of SWCNT based TCFs with similar performance. Especially, these high-yield DWCNTs films contain 'small' bundles with around 50% of CNTs being individual, which is completely different from other FC-CVD results for SWCNTs produced at much lower yield. Moreover, the large-diameter DWCNTs will flatten at the junctions, which may provide a larger contact area between the tubes and accordingly may reduce the contact resistance. In addition, we discuss our recent research efforts towards synthesizing semiconducting SWNTs from liquid precursors (ethanol, methanol, isopropanol) using FC-CVD.



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